



# **isc Silicon PNP Power Transistor**

#### **DESCRIPTION**

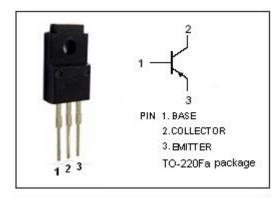
- · High DC Current Gain-
  - : h<sub>FE</sub>= 150(Min.) @ I<sub>C</sub>= -1A
- · High Switching Speed
- · Low Collector Saturation Voltage-
  - :  $V_{CE(sat)}$ = -0.4V(Max)@ I<sub>C</sub>= -3A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

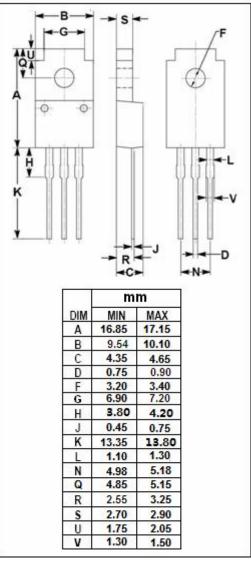


· Designed for high current switching applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-60	٧	
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-7	V	
lc	Collector Current-Continuous	-5	Α	
I <sub>B</sub>	Base Current-Continuous	-1	А	
Pc	Collector Power Dissipation @T <sub>a</sub> =25 ℃	2	W	
	Collector Power Dissipation @T <sub>C</sub> =25℃	20		
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	







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2SA1387

#### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA; I <sub>B</sub> = 0	-50			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -75mA			-0.4	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -75mA			-1.2	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -50V; I <sub>E</sub> = 0			-1	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -7V; I <sub>C</sub> = 0			-1	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -1V	150		400	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -3A ; V <sub>CE</sub> = -1V	70			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>E</sub> = 1A; V <sub>CE</sub> = -4V		80		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f <sub>test</sub> = 1MHz		200		pF

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